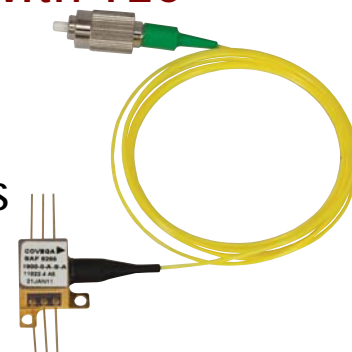


Tunable Laser Gain Chip with TEC

SAF1900S



Description

The SAF1900S 1900 nm Single-Angled-Facet (SAF) gain chip (AR-coated laser diode) features an angled waveguide, AR coating, and a proven gain structure, which gives designers of external cavity lasers (ECLs) the highest power and widest tuning range available in the market. The butterfly assembly features a TEC and an optical isolator to improve the stability of the laser.

Laser Cavity Performance*

*Different external laser cavities will produce different performance specifications. The data given here is only valid for the specified reference cavity.



		SAF1900S		
		Min	Typical	Max
Reference Laser Cavity		Littman Cavity: TLK-L1900M		
Center Wavelength		1870 nm	1900 nm	1930 nm
Tuning Range ^a		130 nm	170 nm	-
Peak Power		5 mW	7 mW	-
Wavelength Tuning Resolution		4 pm	-	-
Tuning Speed		-	-	57 nm/s
Linewidth		-	100 kHz	130 kHz
Side Mode Suppression Ratio (SMSR)		30 dB	45 dB	-
Polarization Extinction Ratio		-	-	-
Power Stability ^b	30 s	1%	-	-
	24 hr	10%	-	-
Wavelength Stability ^b	30 s	-	-	2 pm
	24 hr	-	-	100 pm

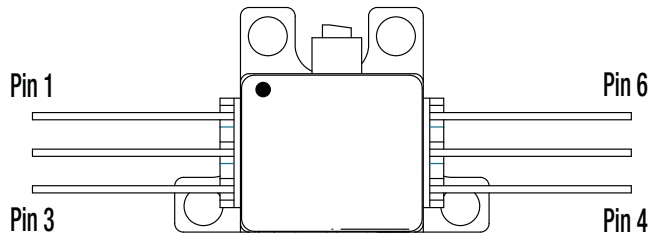
^a 10 dB, ^b Running open loop, measured using ITC4020 current controller.

ASE Performance

T_{OP} = 25 °C

		SAF1900S		
		Min	Typical	Max
Center Wavelength		1850 nm	1930 nm	1990 nm
3 dB Bandwidth		100 nm	150 nm	-
Operating Current		-	400 mA	-
Chip Forward Voltage		-	-	2 V
Gain Ripple, RMS ^a		-	-	1.5 dB
Power, Front Facet ^b		0.07 mW	-	-

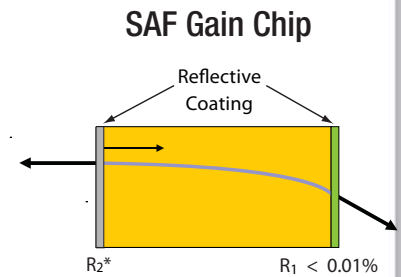
^a @ I_{OP}, ^b Measured using OSA with 0.1 nm resolution bandwidth; ^bFree-space output power



- | Pin Identification | |
|--------------------|-------------|
| 1. | TEC + |
| 2. | Thermistor |
| 3. | Thermistor |
| 4. | Dev. Anode |
| 5. | Dev Cathode |
| 6. | TEC - |

Additional Specifications

	SAF1900S		
	Min	Typical	Max
Chip Gain ^a	-	18 dB	-
Angled Facet Reflectivity ^b (R ₁)	-	.005%	0.01%
Normal Facet Reflectivity (R ₂)	-	20%	-
Lateral Beam Exit Angle	-	26.5°	-
Beam Divergence (FWHM)	θ_T	35°	-
	θ_L	19°	-
Operating Current ^c	-	500 mA	800 mA
Operating Temperature (Non-Condensing)	-	25 °C	-
TEC Forward Voltage	-	-	3.6 V
TEC Forward Current	-	-	2.1 A
Chip Length	-	2 mm	-
Waveguide Refractive Index	-	3.2	-
Astigmatism	-	1 μ m	3 μ m
Fiber Type	SM2000		
Fiber Connector	FC/APC		
Peak Optical Isolation	-	-	-
Fiber Coupling Efficiency	-	50%	-



*R₂ is between 10 and 30%, depending on model.

^a Single pass optical gain at center of gain curve; ^b SAF chip reflectivity diagram (see below); ^c @ T_{OP}

Graphs

